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SuperSOT[™]-3

NPN Low Saturation Transistor

These devices are designed with high current gain and low saturation voltage with collector currents up to 3A continuous. Sourced from Process NC.

Absolute Maximum Ratings* T_{A = 25°C unless otherwise noted}

Symbol	Parameter	FSB649	Units
VCEO	Collector-Emitter Voltage	25	V
V _{CBO}	Collector-Base Voltage	35	V
V _{EBO}	Emitter-Base Voltage	5	V
Ic	Collector Current - Continuous	3	Α
T _{J,} T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150°C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Мах	Units
		FSB649	
PD	Total Device Dissipation	500	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	250	°C/W
		•	

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Symbol	Al Characteristics T _{A = 25°C unless o} Parameter	Test Conditions	Min	Max	Units
-					
	RACTERISTICS		25		V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 10 mA			
3V _{CBO}	Collector-Base Breakdown Voltage	I _C = 100 μA	35		V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E = 100 μA	5		V
СВО	Collector Cutoff Current	V _{CB} = 30 V		100	nA
		$V_{CB} = 30 \text{ V}, \text{ T}_{A} = 100^{\circ}\text{C}$		10	uA
EBO	Emitter Cutoff Current	$V_{EB} = 4V$		100	nA
	ACTERISTICS* DC Current Gain		70		_
FE		$I_{C} = 50 \text{ mA}, V_{CE} = 2 \text{ V}$ $I_{C} = 1 \text{ A}, V_{CE} = 2 \text{ V}$	100	300	
		$I_{C} = 2 A, V_{CE} = 2 V$	75		
		$I_{C} = 6 \text{ A}, V_{CE} = 2 \text{ V}$	15		
CE(sat)	Collector-Emitter Saturation Voltage	I _C = 1 A, I _B = 100 mA		300	mV
VGE(sat)		$I_{\rm C} = 3 \text{ A}, I_{\rm B} = 300 \text{ mA}$		600	
BE(sat)	Base-Emitter Saturation Voltage	I _C = 1 A, I _B = 100 mA		1.25	V
BE(on)	Base-Emitter On Voltage	$I_{C} = 1 \text{ A}, V_{CE} = 2 \text{ V}$		1	V
		10 - 17, VCE - 2 V			
MALL SI	GNAL CHARACTERISTICS	1			
obo	Output Capacitance	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0, \text{ f} = 1 \text{MHz}$		50	pF
Г	Transition Frequency	$I_{C} = 100 \text{ mA}, V_{CE} = 5 \text{ V}, \text{ f}=100 \text{ MHz}$	150		-

FSB649

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